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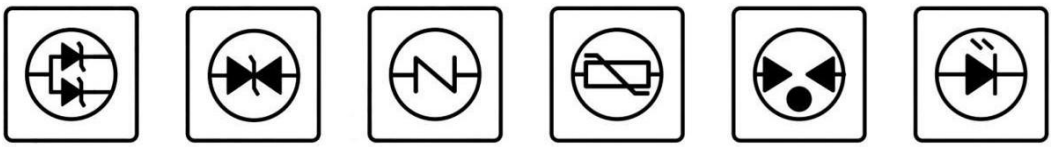
SEMICONDUCTOR



1.5SMCXXXA(CA)(MS)

Product specification

Features

- For surface mounted applications in order to optimize board space
- Low profile package
- Built-in strain relief
- Glass passivated junction
- Low inductance
- Excellent clamping capability
- 1500W peak pulse power capability at 10/1000μs waveform, repetition rate (duty cycle): 0.01%
- Fast response time
- Typical I_R less than 1μA above 12V
- High Temperature soldering: 260℃/10 seconds at terminals
- Plastic package has underwriters laboratory flammability 94V-0
- Meets MSL level 1, per J-STD-020

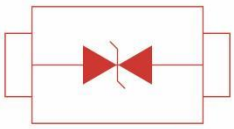
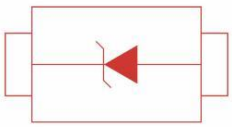
Mechanical Data

- Case: JEDEC DO-214AB. Molded plastic over glass passivated junction
- Terminal: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode except bi-directional models
- Standard Packaging: 16mm tape (EIA STD RS-481)
- Weight: 0.26g

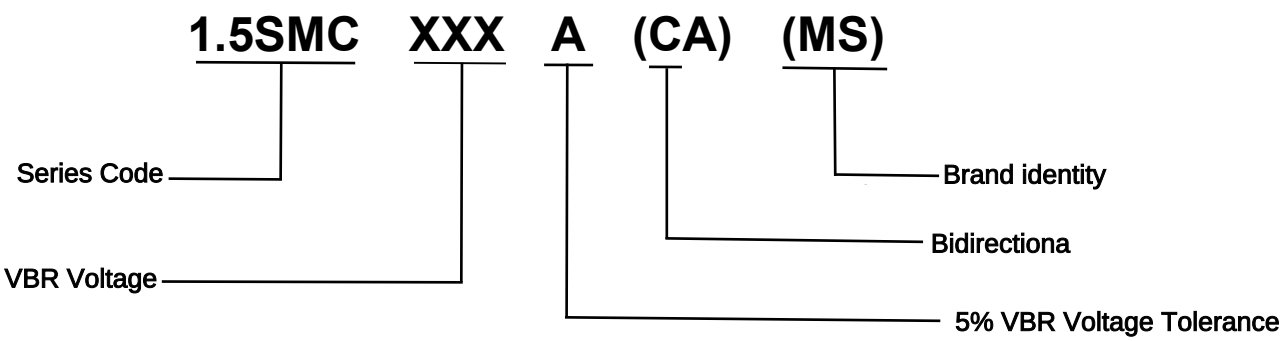
Applications

- I/O interface
- AC/DC power supply
- Low frequency signal transmission line (RS232, RS485, etc.)

Reference News

PACKAGE OUTLINE	PIN CONFIGURATION	Marking Information
		
Unipolar		
		
Bipolar		

Part number code



Maximum Ratings and Characteristics

Ratings at 25℃ ambient temperature unless otherwise specified.

Rating	Symbol	Value	Units
Peak pulse power dissipation at 10/1000μs waveform (Note1, Note2, Fig.1)	P_{PPM}	1500	Watts
Peak pulse current of at 10/1000μs waveform (Note 1, Fig.3)	I_{PPM}	See Table	Amps
Steady state power dissipation at T_A=50℃ (Fig.5)	$P_{M(AV)}$	6.5	Watts
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load, (JEDEC Method) (Note3, Fig.6)	I_{FSM}	200	Amps
Operating junction and Storage Temperature Range.	T_J,T_{STG}	-55 to +150	℃
Typical thermal resistance junction to lead	$R_{\theta JL}$	15	℃/W
Typical thermal resistance junction to ambient	$R_{\theta JA}$	75	℃/W

Notes: 1. Non-repetitive current pulse, per Fig.3 and derated above T_A=25℃ per Fig.2.
2. Mounted on 8.0mm×8.0mm copper pads to each terminal.
3. 8.3ms single half sine-wave, or equivalent square wave, duty cycle=4 pulses per minutes maximum.

Electrical Characteristics (T_A=25℃)

Part Number		Device Marking Code		Reverse Stand-Off Voltage	Breakdown Voltage @I_T	Test Current	Maximum Clamping Voltage@I_{PP}	Peak Pulse Current	Reverse Leakage @ V_{RWM}
Unidirectional	Bidirectional	UNI	BI	V_{RWM}(V)	V_{BR}(V)	I_T(mA)	V_C(V)	I_{PP}(A)	I_R(μA)
1.5SMC6.8A	1.5SMC6.8CA	6V8A	6V8C	5.80	6.45~7.14	10	10.5	144.8	1000
1.5SMC7.5A	1.5SMC7.5CA	7V5A	7V5C	6.40	7.13~7.88	10	11.3	134.5	500
1.5SMC8.2A	1.5SMC8.2CA	8V2A	8V2C	7.02	7.79~8.61	10	12.1	125.6	200
1.5SMC9.1A	1.5SMC9.1CA	9V1A	9V1C	7.78	8.65~9.55	1	13.4	113.4	50
1.5SMC10A	1.5SMC10CA	10A	10C	8.55	9.50~10.50	1	14.5	104.8	10
1.5SMC11A	1.5SMC11CA	11A	11C	9.40	10.50~11.60	1	15.6	97.4	5
1.5SMC12A	1.5SMC12CA	12A	12C	10.20	11.40~12.60	1	16.7	91.0	5
1.5SMC13A	1.5SMC13CA	13A	13C	11.10	12.40~13.70	1	18.2	83.5	1
1.5SMC15A	1.5SMC15CA	15A	15C	12.80	14.30~15.80	1	21.2	71.7	1
1.5SMC16A	1.5SMC16CA	16A	16C	13.60	15.20~16.80	1	22.5	67.6	1
1.5SMC18A	1.5SMC18CA	18A	18C	15.30	17.10~18.90	1	25.2	60.3	1
1.5SMC20A	1.5SMC20CA	20A	20C	17.10	19.00~21.00	1	27.7	54.9	1
1.5SMC22A	1.5SMC22CA	22A	22C	18.80	20.90~23.10	1	30.6	49.7	1
1.5SMC24A	1.5SMC24CA	24A	24C	20.50	22.80~25.20	1	33.2	45.8	1
1.5SMC27A	1.5SMC27CA	27A	27C	23.10	25.70~28.40	1	37.5	40.5	1
1.5SMC30A	1.5SMC30CA	30A	30C	25.60	28.50~31.50	1	41.4	36.7	1
1.5SMC33A	1.5SMC33CA	33A	33C	28.20	31.40~34.70	1	45.7	33.3	1
1.5SMC36A	1.5SMC36CA	36A	36C	30.80	34.20~37.80	1	49.9	30.5	1
1.5SMC39A	1.5SMC39CA	39A	39C	33.30	37.10~41.00	1	53.9	28.2	1

1.5SMCXXXA(CA)(MS)

Part Number		Device Marking Code		Reverse Stand-Off Voltage	Breakdown Voltage @I_T	Test Current	Maximum Clamping Voltage@I_{PP}	Peak Pulse Current	Reverse Leakage @V_{RWM}
Unidirectional	Bidirectional	UNI	BI	V_{RWM}(V)	V_{BR}(V)	I_T(mA)	V_C(V)	I_{PP}(A)	I_R(μA)
1.5SMC43A	1.5SMC43CA	43A	43C	36.80	40.90~45.20	1	59.3	25.6	1
1.5SMC47A	1.5SMC47CA	47A	47C	40.20	44.70~49.40	1	64.8	23.5	1
1.5SMC51A	1.5SMC51CA	51A	51C	43.60	48.50~53.60	1	70.1	21.7	1
1.5SMC56A	1.5SMC56CA	56A	56C	47.80	53.20~58.80	1	77.0	19.7	1
1.5SMC62A	1.5SMC62CA	62A	62C	53.00	58.90~65.10	1	85.0	17.9	1
1.5SMC68A	1.5SMC68CA	68A	68C	58.10	64.60~71.40	1	92.0	16.5	1
1.5SMC75A	1.5SMC75CA	75A	75C	64.10	71.30~78.80	1	103.0	14.8	1
1.5SMC82A	1.5SMC82CA	82A	82C	70.10	77.90~86.10	1	113.0	13.5	1
1.5SMC91A	1.5SMC91CA	91A	91C	77.80	86.50~95.50	1	125.0	12.2	1
1.5SMC100A	1.5SMC100CA	100A	100C	85.50	95.00~105.00	1	137.0	11.1	1
1.5SMC110A	1.5SMC110CA	110A	110C	94.00	105.00~116.00	1	152.0	10.0	1
1.5SMC120A	1.5SMC120CA	120A	120C	102.00	114.00~126.00	1	165.0	9.2	1
1.5SMC130A	1.5SMC130CA	130A	130C	111.00	124.00~137.00	1	179.0	8.5	1
1.5SMC150A	1.5SMC150CA	150A	150C	128.00	143.00~158.00	1	207.0	7.3	1
1.5SMC160A	1.5SMC160CA	160A	160C	136.00	152.00~168.00	1	219.0	6.9	1
1.5SMC170A	1.5SMC170CA	170A	170C	145.00	162.00~179.00	1	234.0	6.5	1
1.5SMC180A	1.5SMC180CA	180A	180C	154.00	171.00~189.00	1	246.0	6.2	1
1.5SMC200A	1.5SMC200CA	200A	200C	171.00	190.00~210.00	1	274.0	5.5	1
1.5SMC220A	1.5SMC220CA	220A	220C	185.00	209.00~231.00	1	328.0	4.6	1
1.5SMC250A	1.5SMC250CA	250A	250C	214.00	237.00~263.00	1	344.0	4.4	1
1.5SMC300A	1.5SMC300CA	300A	300C	256.00	285.00~315.00	1	414.0	3.7	1
1.5SMC350A	1.5SMC350CA	350A	350C	300.00	332.00~368.00	1	482.0	3.2	1
1.5SMC400A	1.5SMC400CA	400A	400C	342.00	380.00~420.00	1	548.0	2.8	1
1.5SMC440A	1.5SMC440CA	440A	440C	376.00	418.00~462.00	1	602.0	2.5	1
1.5SMC480A	1.5SMC480CA	480A	480C	408.00	456.00~504.00	1	658.0	2.3	1
1.5SMC510A	1.5SMC510CA	510A	510C	434.00	485.00~535.00	1	698.0	2.1	1
1.5SMC530A	1.5SMC530CA	530A	530C	450.00	503.50~556.50	1	725.0	2.1	1
1.5SMC540A	1.5SMC540CA	540A	540C	459.00	513.00~567.00	1	740.0	2.0	1
1.5SMC550A	1.5SMC550CA	550A	550C	467.00	522.50~577.50	1	760.0	2.0	1

Ratings and Characteristic Curves (T_A=25℃ unless otherwise noted)

Figure 1. Peak Pulse Power Rating Curve

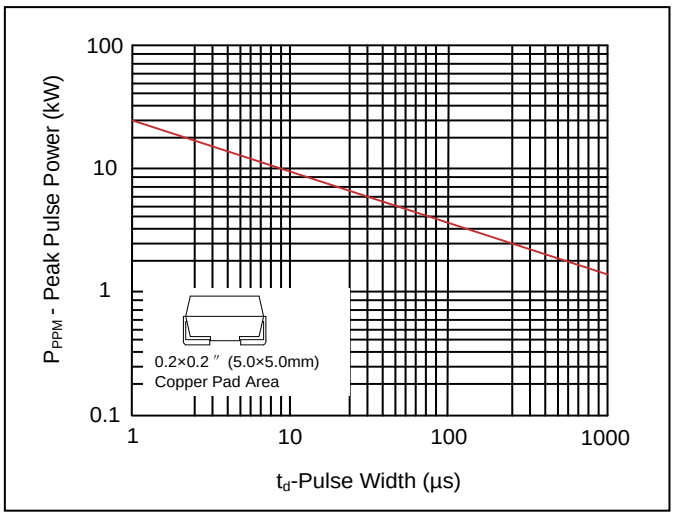


Figure 2. Pulse Derating Curve

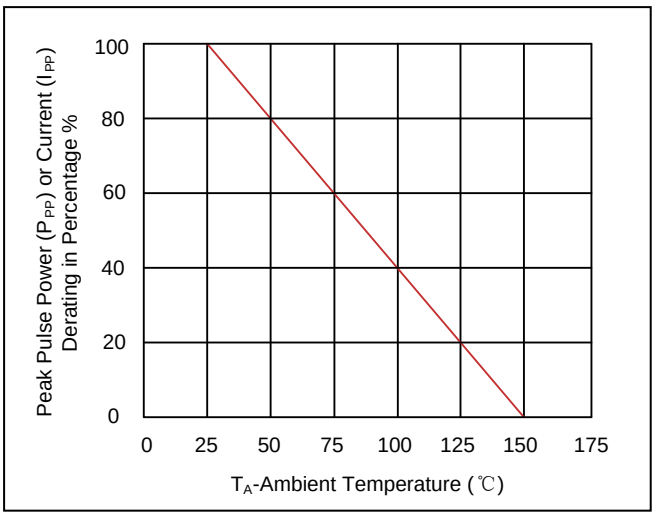


Figure 3. Pulse Waveform

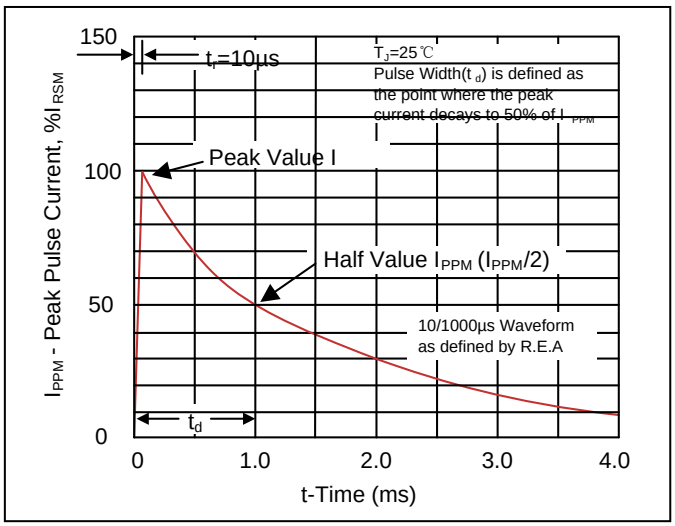


Figure 4. Typical Junction Capacitance

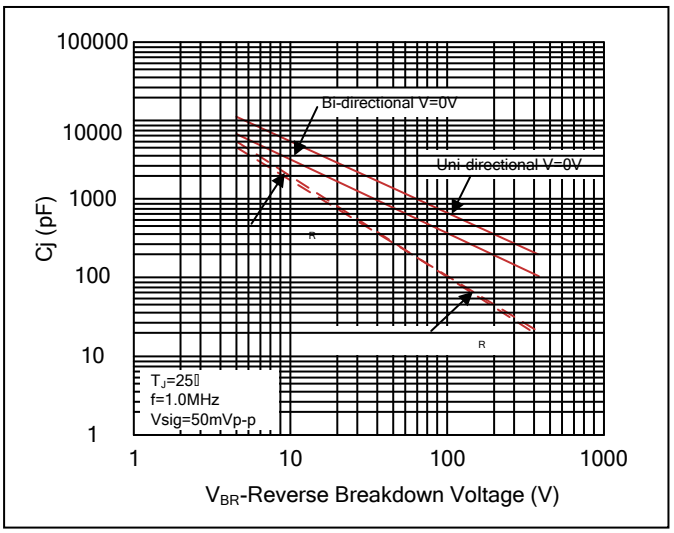


Figure 5. Steady State Power Dissipation Derating Curve

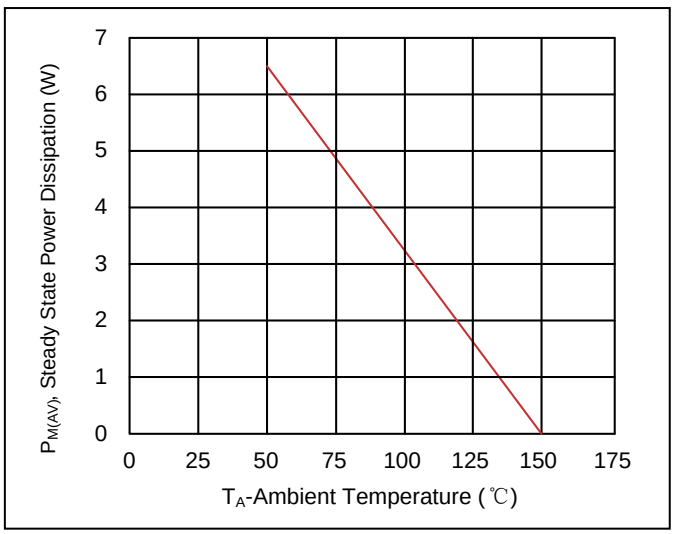
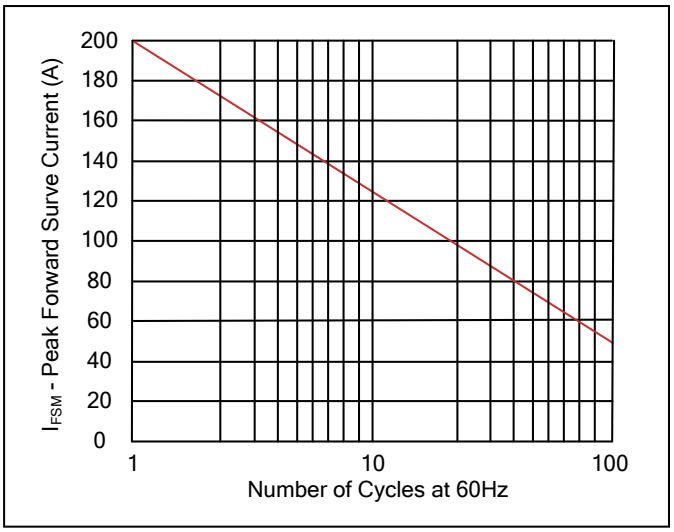
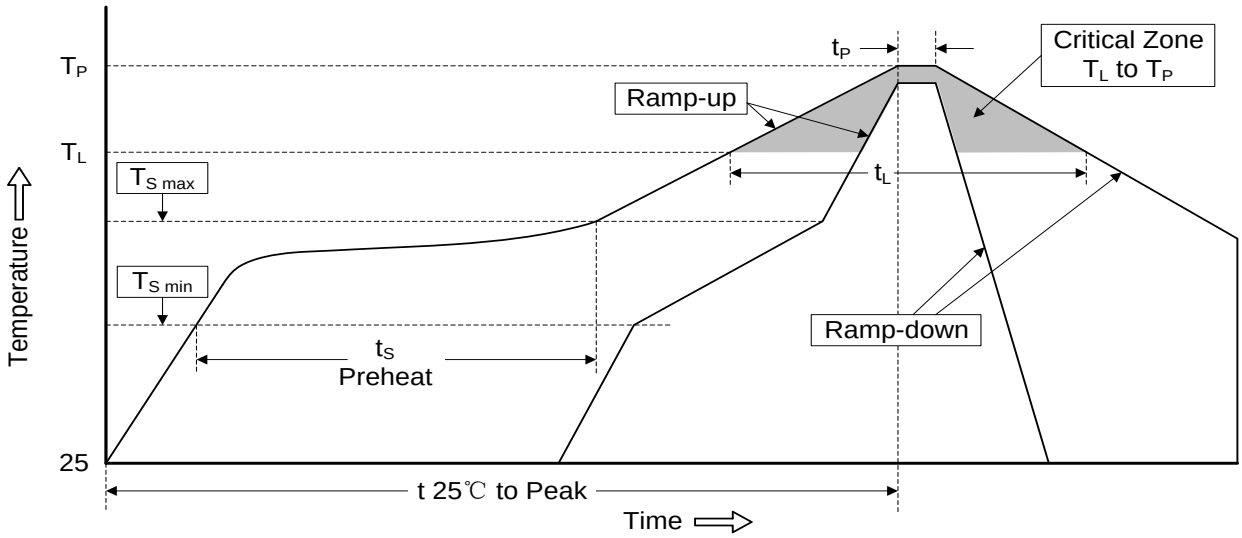


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Only



Recommended Soldering Conditions

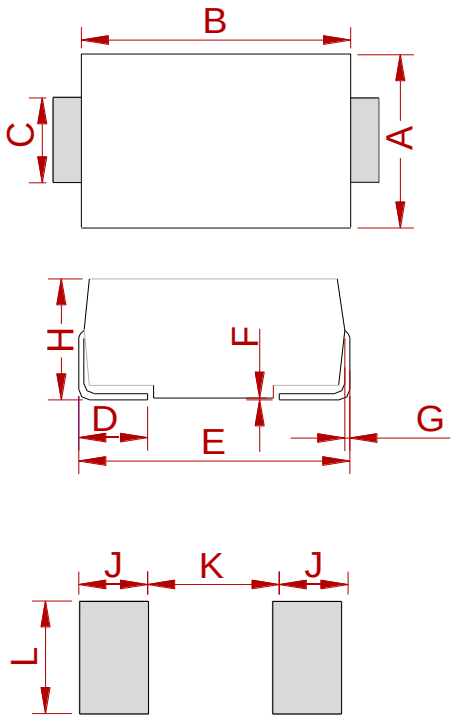
Reflow Soldering



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3℃/second max.
Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_S)	 150℃ 200℃ 60-180 seconds
$T_{S\ max}$ to T_L -Ramp-up Rate	 3℃/second max.
Time maintained above: -Temperature (T_L) -Time (t_L)	 217℃ 60-150 seconds
Peak Temperature (T_P)	260℃
Time within 5℃ of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down Rate	6℃/second max.
Time 25℃ to Peak Temperature	8 minutes max.

PACKAGE MECHANICAL DATA



DO-214AB (SMC)

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	5.75	6.25	0.226	0.246
B	6.90	7.40	0.272	0.291
C	2.75	3.25	0.108	0.128
D	0.95	1.52	0.037	0.060
E	7.70	8.20	0.303	0.323
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.15	2.62	0.085	0.103
J	2.40		0.094	
K		4.20		0.165
L	3.30		0.130	

REEL SPECIFICATION

P/N	PKG	QTY
1.5SMCXXXA(CA)(MS)	SMC	3000

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